

# RJK6018DPK

# Silicon N Channel MOS FET High Speed Power Switching

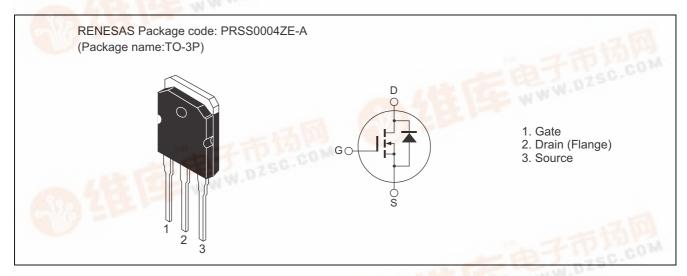
REJ03G1537-0100 Rev.1.00 Apr 04, 2007

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#### **Features**

- Low on-resistance
- Low leakage current
- High speed switching

#### **Outline**



#### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	600	V
Gate to source voltage	$V_{GSS}$	±30	V
Drain current	I <sub>D</sub>	30	A
Drain peak current	I <sub>D (pulse)</sub> Note1	90	A
Body-drain diode reverse drain current	I <sub>DR</sub>	30	Access
Body-drain diode reverse drain peak current	I <sub>DR</sub> (pulse)	90	M M - B - A
Avalanche current	I <sub>AP</sub> Note3	6	Α
Avalanche energy	E <sub>AR</sub> Note3	1.9	mJ
Channel dissipation	Pch Note2	200	W
Channel to case thermal impedance	θch-c	0.625	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

- 2. Value at Tc = 25°C
- 3. STch =  $25^{\circ}$ C, Tch  $\leq 150^{\circ}$ C



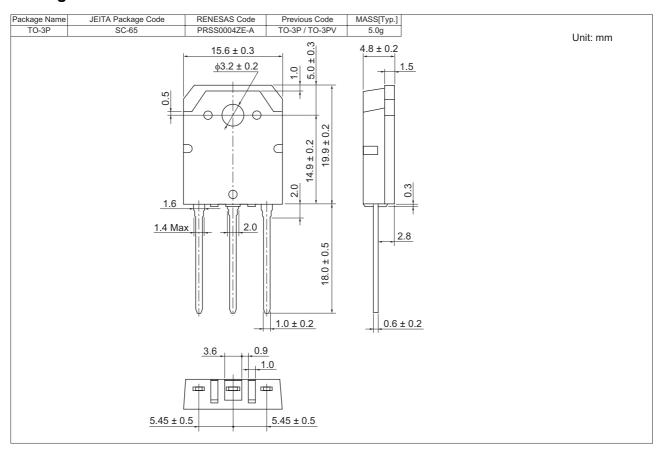
#### **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	600	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 600 \text{ V}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state resistance	R <sub>DS(on)</sub>	_	0.200	0.235	Ω	$I_D = 15 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	4100	_	pF	$V_{DS} = 25 V$ $V_{GS} = 0$ $f = 1 MHz$
Output capacitance	Coss	_	380	_	pF	
Reverse transfer capacitance	Crss	_	37	_	pF	
Turn-on delay time	t <sub>d(on)</sub>	_	50	_	ns	$I_D = 15 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 20 \Omega$ $Rg = 10 \Omega$
Rise time	t <sub>r</sub>	_	88	_	ns	
Turn-off delay time	t <sub>d(off)</sub>	_	140	_	ns	
Fall time	t <sub>f</sub>	_	81	_	ns	
Total gate charge	Qg	_	92	_	nC	V <sub>DD</sub> = 480 V V <sub>GS</sub> = 10 V I <sub>D</sub> = 30 A
Gate to source charge	Qgs	_	22	_	nC	
Gate to drain charge	Qgd	_	38	_	nC	
Body-drain diode forward voltage	$V_{DF}$	_	0.90	1.50	V	$I_F = 30 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	480	_	ns	$I_F = 30 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

## **Package Dimensions**



# **Ordering Information**

Part No.	Quantity	Shipping Container
RJK6018DPK-00	360 pcs	Box (Tube)

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Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510